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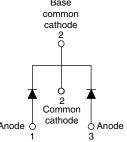
Vishay Semiconductors

Hyperfast Rectifier, 2 x 15 A FRED Pt®



TO-220AB

Diode variation



Common cathode

| | Ba com cath | mon ode | |
|---------|-------------------|------------------------|---------|
| Anode 0 | Com |) 2 nmon node | Anode 3 |

FEATURES

- Hyperfast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





HALOGEN **FREE**

| PRODUCT SUMMARY | | | | |
|--------------------|--|--|--|--|
| TO-220AB | | | | |
| 2 x 15 A | | | | |
| 300 V | | | | |
| 0.85 V | | | | |
| See Recovery table | | | | |
| 175 °C | | | | |
| | | | | |

DESCRIPTION / APPLICATIONS

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|------------|-----------------------------------|-------------------------|-------------|-------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Peak repetitive reverse voltage | | V_{RRM} | | 300 | V | |
| Average rectified forward current | per diode | I _{F(AV)} | T _C = 153 °C | 15 | | |
| | per device | | | 30 | Α | |
| Non-repetitive peak surge current | | I _{FSM} | T _C = 25 °C | 150 | | |
| Operating junction and storage temperatures | | T _J , T _{Stg} | | -65 to +175 | °C | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|-------------------------------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I ID = 100 UA | | - | - | | |
| Forward voltage | VF | I _F = 15 A | - | 1.0 | 1.25 | V | |
| | v _F | I _F = 15 A, T _J = 125 °C | - | 0.85 | 0.95 | | |
| Reverse leakage current I _R | | V _R = V _R rated | - | - | 40 | | |
| | | T _J = 125 °C, V _R = V _R rated | - | 8 | 200 | μΑ | |
| Junction capacitance | C _T | V _R = 300 V | - | 38 | - | pF | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8 | - | nH | |



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| DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified) | | | | | | | |
|---|------------------|--|--|--|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1 A, dI_F/dt = 50$ | $0 \text{ A/}\mu\text{s}, \text{ V}_{\text{R}} = 30 \text{ V}$ | - | - | 36 | |
| Reverse recovery time | t _{rr} | $I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | - | 30 | |
| | | T _J = 25 °C | I _F = 15 A | - | 33 | - | ns |
| | | T _J = 125 °C | | - | 48 | - | |
| Peak recovery current | I _{RRM} | T _J = 25 °C | | - | 2.8 | - | Α |
| | | IRRM | T _J = 125 °C | dI _F /dt = 200 A/μs V _R = 200 V | - | 6.5 | - |
| Reverse recovery charge Q _{rr} | Q _{rr} | T _J = 25 °C | *H - 200 * | = | 46 | - | nC |
| | | T _J = 125 °C | | - | 160 | - | no no |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|------------|----------|------|-------|--|
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | -65 | = | 175 | °C | |
| Thermal resistance, junction to case per diode | R_{thJC} | - | - | 1.4 | °C/W | |
| Marking device | | Case style | TO-220AB | 30C | ГН03 | |

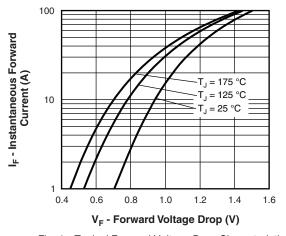


Fig. 1 - Typical Forward Voltage Drop Characteristics

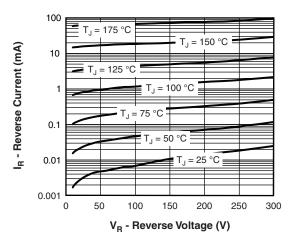


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

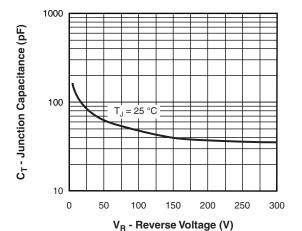


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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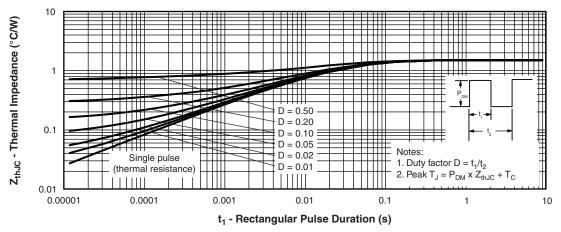


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

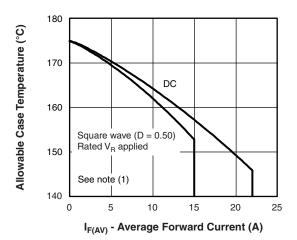


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

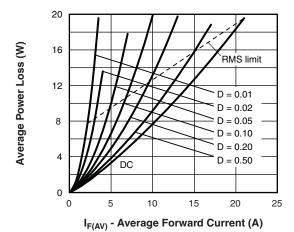


Fig. 6 - Forward Power Loss Characteristics

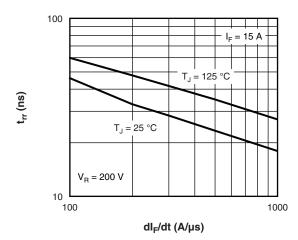


Fig. 7 - Typical Reverse Recovery Time vs. dI_{F}/dt

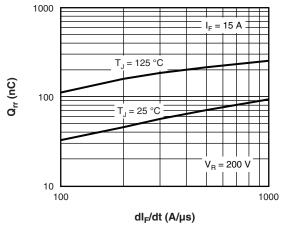


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = Rated V_R

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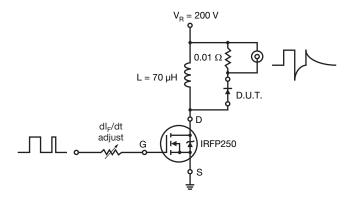
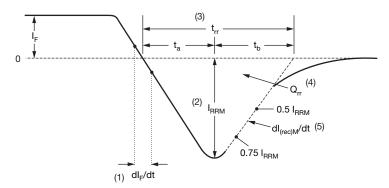


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) dI_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

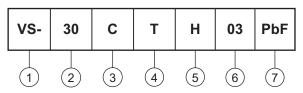
Fig. 10 - Reverse Recovery Waveform and Definitions

VS-30CTH03PbF, VS-30CTH03-N3

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ORDERING INFORMATION TABLE

Device code



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2 - Current rating (30 = 30 A)

Circuit configuration:

C = common cathode

4 - Package:

T = TO-220

5 - H = hyperfast recovery

Voltage rating (03 = 300 V)

7 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-N3 = halogen-free, RoHS-compliant and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-30CTH03PbF | 50 | 1000 | Antistatic plastic tube | | | |
| VS-30CTH03-N3 | 50 | 1000 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|---|-------------|--------------------------|--|--|
| Dimensions TO-220AB <u>www.vishay.com/doc?95222</u> | | | | |
| Dout modeling information | TO-220ABPbF | www.vishay.com/doc?95225 | | |
| Part marking information | TO-220AB-N3 | www.vishay.com/doc?95028 | | |



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